TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC393F,TC74VHC393FN,TC74VHC393FT

Dual Binary Counter

The TC74VHC393 is an advanced high speed CMOS 4-BIT BINARY COUNTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It contains two independent counter circuits in one package, so that counting or frequency division of eight binary bits can be achieved with one IC.

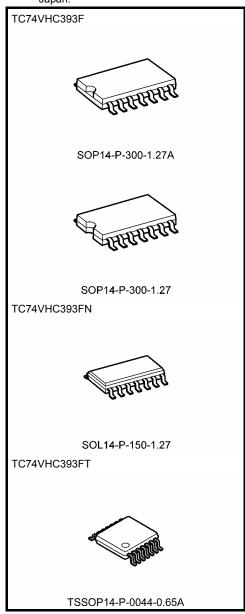
This device changes state on the negative going transition of the $\overline{\text{CLOCK}}$ pulse. The counter can be reset to "0" (QA to QD = "L") by a high at the CLEAR input regardless of other inputs.

An input protection circuit ensures that 0 to 5.5~V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5~V to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $f_{max} = 170 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{°C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Low noise: $V_{OLP} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS393

Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

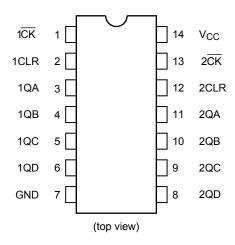
 SOP14-P-300-1.27A
 : 0.18 g (typ.)

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 : 0.18 g (typ.)

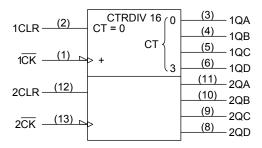
 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

Pin Assignment



IEC Logic Symbol

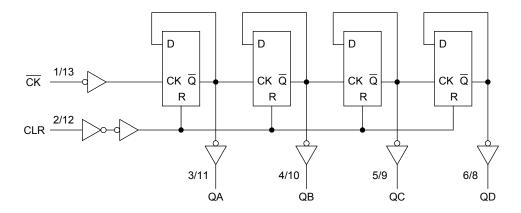


Truth Table

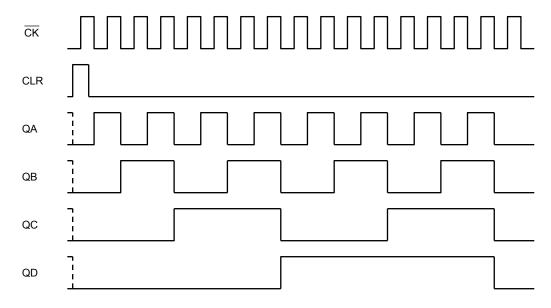
Inp	uts	Outputs							
CK	CLR	QA	QB	QC	QD				
Х	Н	L	L	L	L				
\Box	L	Count Up							
	L	No Change							

X: Don't care

System Diagram



Timing Chart



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to 5.5	٧	
Output voltage	V _{OUT}	0 to V _{CC}	٧	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rice and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	no/\/	
Input rise and fall time	ai/uv	0 to 20 ($V_{CC} = 5 \pm 0.5 \text{ V}$)	ns/V	

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
		V _C		V _{CC} (V)	Min	Тур.	Max	Min	Max	
High-level input		-		2.0	1.50	_	_	1.50	_	٧
voltage	V _{IH}			3.0 to 5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_	
Low-level input				2.0	_	_	0.50	_	0.50	
voltage	V _{IL}		_	3.0 to 5.5	_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	V
	Voн	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
High-level output voltage				4.5	4.4	4.5	_	4.4	_	V
			I _{OH} = −4 mA	3.0	2.58	_	_	2.48	_	
			I _{OH} = -8 mA	4.5	3.94	-	_	3.80	_	
	V _{OL}	V _{IN} = V _{IH} or V _{IL}		2.0	_	0.0	0.1	_	0.1	
			I _{OL} = 50 μA	3.0	_	0.0	0.1	_	0.1	
Low-level output voltage				4.5	_	0.0	0.1	_	0.1	V
			I _{OL} = 4 mA	3.0	_	_	0.36	_	0.44	
			I _{OL} = 8 mA	4.5	_	_	0.36	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	ı	±0.1	_	±1.0	μΑ
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or	GND	5.5	_	_	4.0	_	40.0	μΑ

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Characteristics Symbol		Test Condition			Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t _{w (H)}		3.3 ± 0.3	_	5.0	5.0	20
(CK)	t _{w (L)}	_	5.0 ± 0.5	_	5.0	5.0	ns
Minimum pulse width	4	-	3.3 ± 0.3	_	5.0	5.0	20
(CLR)	t _{w (H)}		5.0 ± 0.5	_	5.0	5.0	ns
Minimum removal time	t _{rem}	-	3.3 ± 0.3	_	5.0	5.0	20
			5.0 ± 0.5	_	4.0	4.0	ns



AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol Te:		est Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	8.6	13.2	1.0	15.5	ns
Propagation delay time	t _{pLH}			50	_	11.1	16.7	1.0	19.0	
(CK -QA)	t _{pHL}		5.0 ± 0.5	15	_	5.8	8.5	1.0	10.0	115
			5.0 ± 0.5	50	_	7.3	10.5	1.0	12.0	
			3.3 ± 0.3	15	_	10.2	15.8	1.0	18.5	
Propagation delay time	t _{pLH}		3.3 ± 0.3	50	_	12.7	19.3	1.0	22.0	ns
(CK -QB)	t _{pHL}	_	5.0 ± 0.5	15	_	6.8	9.8	1.0	11.5	115
,			5.0 ± 0.5	50	_	8.3	11.8	1.0	13.5	
	t _{pLH} t _{pHL}		3.3 ± 0.3 5.0 ± 0.5	15	_	11.7	18.0	1.0	21.0	- ns
Propagation delay time (CK -QC)		_		50	_	14.2	21.5	1.0	24.5	
				15	_	7.7	11.2	1.0	13.0	
				50	_	9.2	13.2	1.0	15.0	
	t _P LH t _P HL	_	3.3 ± 0.3	15	_	13.0	19.7	1.0	23.0	- ns
Propagation delay time				50	_	15.5	23.2	1.0	26.5	
(CK -QD)			5.0 ± 0.5	15	_	8.5	12.5	1.0	14.5	
,				50	_	10.0	14.5	1.0	16.5	
			3.3 ± 0.3	15	_	7.9	12.3	1.0	14.5	
Propagation delay time			3.3 ± 0.3	50	_	10.4	15.8	1.0	18.0	no
(CLR-Qn)	tpHL		5.0 ± 0.5	15	_	5.4	8.1	1.0	9.5	ns -
,			5.0 ± 0.5	50	_	6.9	10.1	1.0	11.5	
			3.3 ± 0.3	15	75	120	_	65	_	
Maximum clock frequency	f _{max} —		3.3 ± 0.3	50	45	65	_	35	_	- MHz
		_	5.0 ± 0.5	15	125	170	_	105	_	
				50	85	115	_	75	_	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)	_	23	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

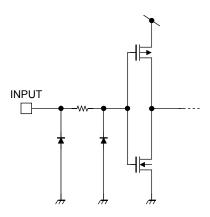
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ (per counter)



Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta =	Unit	
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Offic
Quiet output maximum dynamic V _{OL}	V_{OLP}	C _L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

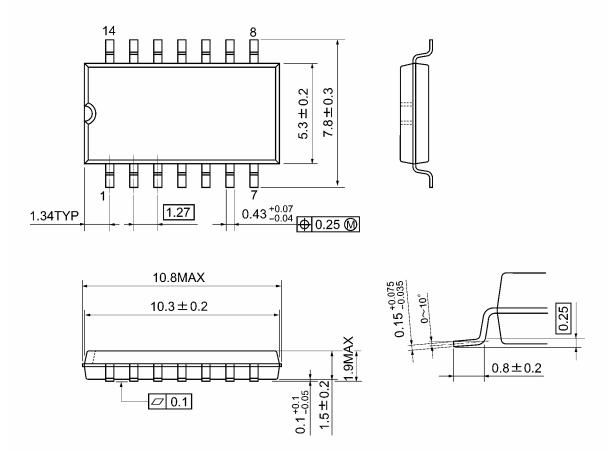
Input Equivalent Circuit



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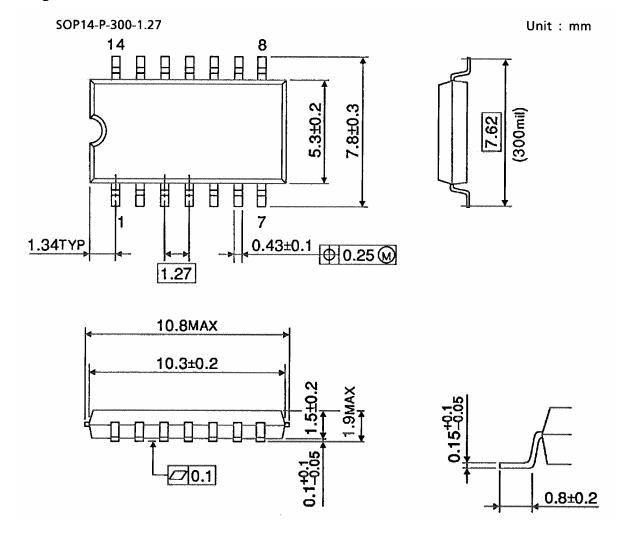
Package Dimensions

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions

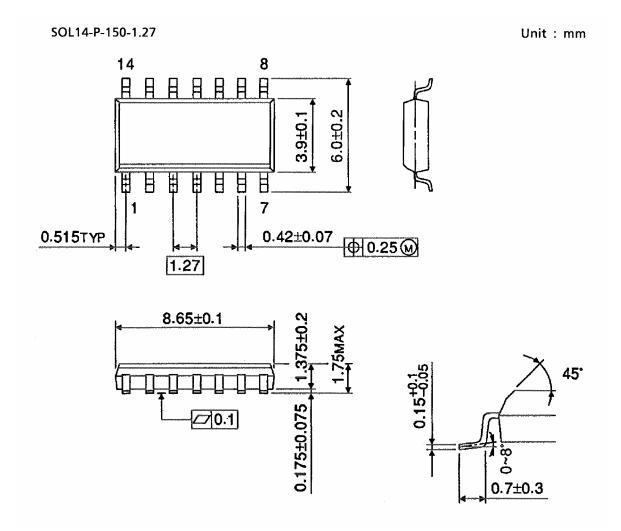


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Weight: 0.18 g (typ.)

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Package Dimensions (Note)



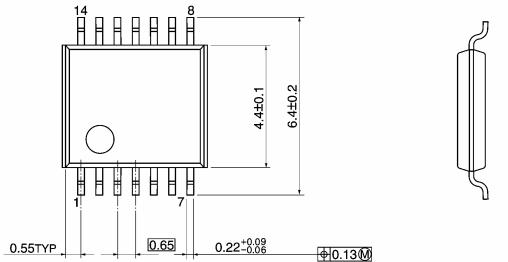
9

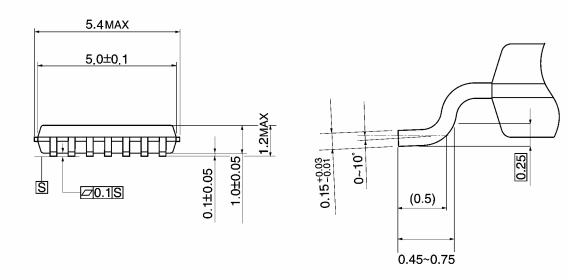
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A Unit: mm





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Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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